**Product data sheet** 

## 1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in an MLPAK33 (SOT8002) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### 2. Features and benefits

- Logic-level compatible
- Trench MOSFET technology
- MLPAK33 package (3.3 x 3.3 mm footprint)

## 3. Applications

- · DC-to-DC converters
- · Battery management
- · Low-side load-switch
- Switching circuits

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	30	V	
$V_{GS}$	gate-source voltage			-20	-	20	V	
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	-	17.3	Α	
Static characte	Static characteristics							
R <sub>DSon</sub>	drain-source on-state	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 11.4 A; T <sub>j</sub> = 25 °C		-	7.7	9.1	mΩ	
	resistance	V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 10.1 A; T <sub>j</sub> = 25 °C		-	9.3	11.6	mΩ	

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.



30 V, N-channel Trench MOSFET

# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	1 2 3 4	D
2	S	source		
3	S	source		G—(FA)
4	G	gate	ि त	mbb076 S
5	D	drain		
6	D	drain		
7	D	drain	MLPAK33 (SOT8002-1)	
8	D	drain		

# 6. Ordering information

### **Table 3. Ordering information**

Type number	Package							
	Name	Description	Version					
PXN9R0-30QL	MLPAK33	plastic thermal enhanced surface mounted package; mini leads; 8 terminals; pitch 0.65 mm; 3.3 x 3.3 x 0.8 mm body	SOT8002-1					

# 7. Marking

### **Table 4. Marking codes**

Type number	Marking code
PXN9R0-30QL	7AM

30 V, N-channel Trench MOSFET

# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	30	V
V <sub>GS</sub>	gate-source voltage			-20	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	17.3	Α
		V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 25 °C	[1]	-	11.4	Α
		V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 100 °C	[1]	-	7.2	Α
		V <sub>GS</sub> = 10 V; T <sub>sp</sub> = 25 °C		-	41.8	Α
I <sub>DM</sub>	peak drain current	T <sub>amb</sub> = 25 °C; single pulse; t <sub>p</sub> ≤ 10 μs		-	90	Α
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	4.5	W
		T <sub>amb</sub> = 25 °C	[1]	-	1.9	W
		T <sub>sp</sub> = 25 °C		-	26	W
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-drai	n diode		'	1		
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	[1]	-	1.7	Α

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.

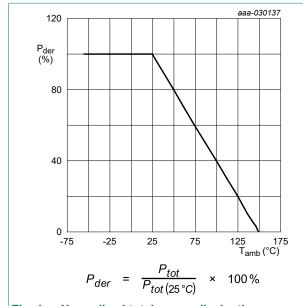


Fig. 1. Normalized total power dissipation as a function of ambient temperature

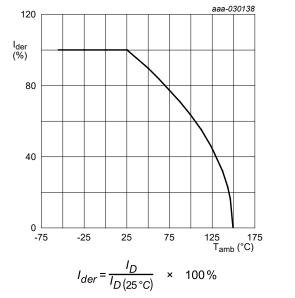


Fig. 2. Normalized continous drain current as a function of ambient temperature

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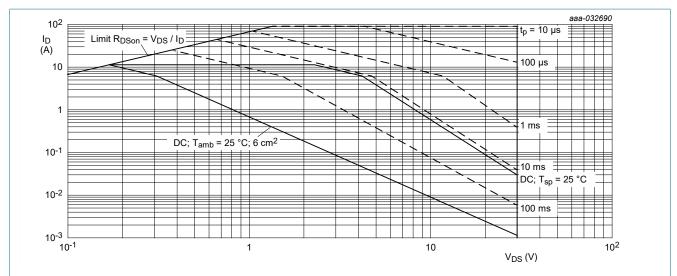


Fig. 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

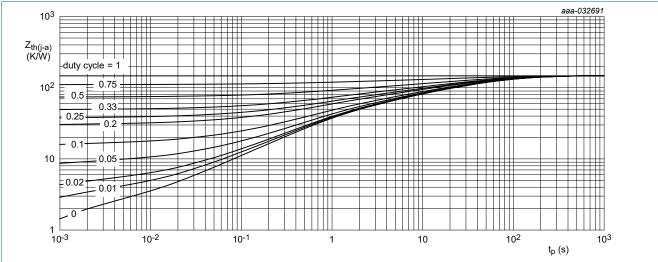
30 V, N-channel Trench MOSFET

### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

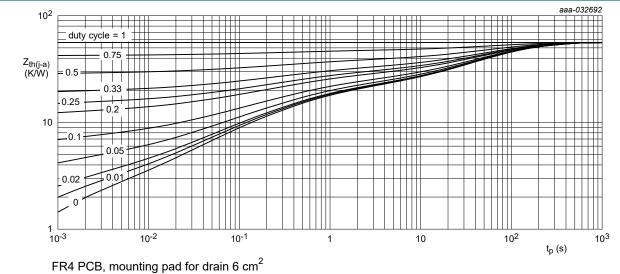
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from	in free air	[1]	-	150	180	K/W
	junction to ambient		[2]	-	55	65	K/W
		in free air; t ≤ 5 s	[2]	-	24	28	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	4	4.8	K/W

- Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.



FR4 PCB, standard footprint

Transient thermal impedance from junction to ambient as a function of pulse duration; typical values Fig. 4.



Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

30 V, N-channel Trench MOSFET

# 10. Characteristics

#### **Table 7. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	cteristics					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	30	-	-	V
$V_{GSth}$	gate-source threshold voltage	$I_D = 250 \mu A; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	1	1.6	2.5	V
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = 30 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	1	μΑ
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = -20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-100	nA
		V <sub>GS</sub> = 20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	100	nA
R <sub>DSon</sub>	drain-source on-state	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 11.4 A; T <sub>j</sub> = 25 °C	-	7.7	9.1	mΩ
	resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 11.4 A; T <sub>j</sub> = 150 °C	-	12.6	14.9	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 10.1 A; T <sub>j</sub> = 25 °C	-	9.3	11.6	mΩ
R <sub>G</sub>	gate resistance	f = 1 MHz	-	1.7	-	Ω
	aracteristics		I			
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = 15 V; $I_{D}$ = 11.4 A; $V_{GS}$ = 10 V; $T_{j}$ = 25 °C	-	13.8	20.7	nC
		$V_{DS} = 15 \text{ V}; I_D = 10.1 \text{ A}; V_{GS} = 4.5 \text{ V};$	-	6.7	10.1	nC
$Q_{GS}$	gate-source charge	T <sub>j</sub> = 25 °C	-	2.1	-	nC
Q <sub>GS(th)</sub>	pre-threshold gate- source charge		-	1.3	-	nC
Q <sub>GS(th-pl)</sub>	post-threshold gate- source charge		-	0.8	-	nC
Q <sub>GD</sub>	gate-drain charge		-	2	-	nC
$V_{GSpl}$	gate-source plateau voltage	$V_{DS} = 15 \text{ V}; I_D = 10.1 \text{ A}; T_j = 25 \text{ °C}$	-	2.5	-	V
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = 15 V; f = 1 MHz; V <sub>GS</sub> = 0 V;	-	865	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	153	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	57	-	pF
t <sub>d(on)</sub>	turn-on delay time	V <sub>DS</sub> = 15 V; I <sub>D</sub> = 10.1 A; V <sub>GS</sub> = 4.5 V;	-	6	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 °C$	-	9	-	ns
t <sub>d(off)</sub>	turn-off delay time	1	-	8	-	ns
t <sub>f</sub>	fall time	1	-	4	-	ns
Source-drai	n diode					
V <sub>SD</sub>	source-drain voltage	$I_S = 1.7 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	0.7	1.2	V
t <sub>rr</sub>	reverse recovery time	I <sub>S</sub> = 1.7 A; dI <sub>S</sub> /dt = -100 A/μs;	-	14	-	ns
Q <sub>r</sub>	recovered charge	$V_{GS} = 4.5 \text{ V}; V_{DS} = 15 \text{ V}; T_j = 25 \text{ °C}$	-	6	-	nC
t <sub>a</sub>	reverse recovery rise time	]	-	9	-	ns
		The state of the s	1	1	1	1

#### 30 V, N-channel Trench MOSFET

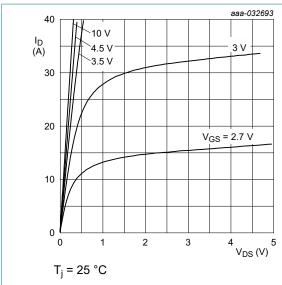
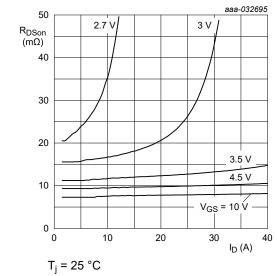
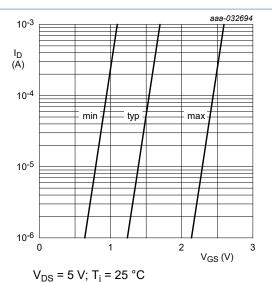


Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values



Drain-source on-state resistance as a function Fig. 8. of drain current; typical values



Sub-threshold drain current as a function of Fig. 7. gate-source voltage

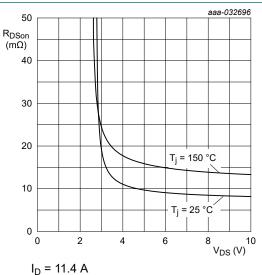


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

#### 30 V, N-channel Trench MOSFET

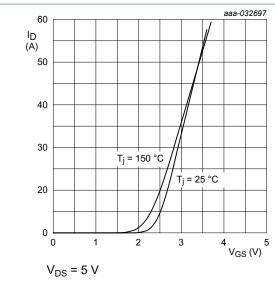


Fig. 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

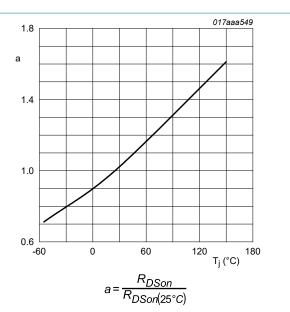


Fig. 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values

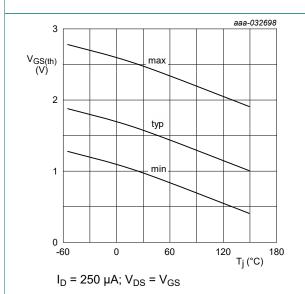


Fig. 12. Gate-source threshold voltage as a function of junction temperature

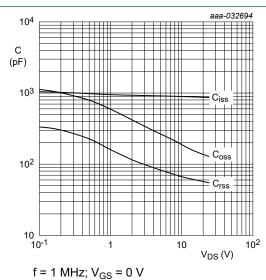


Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

#### 30 V, N-channel Trench MOSFET

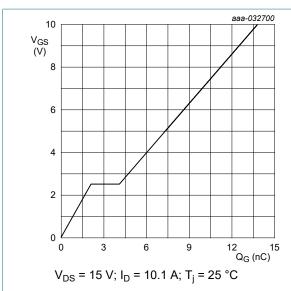


Fig. 14. Gate-source voltage as a function of gate charge; typical values

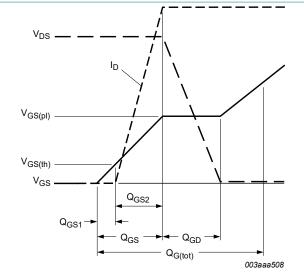


Fig. 15. Gate charge waveform definitions

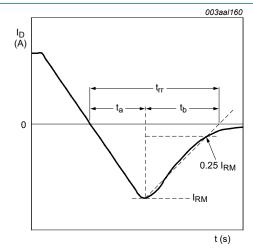


Fig. 16. Reverse recovery timing definition

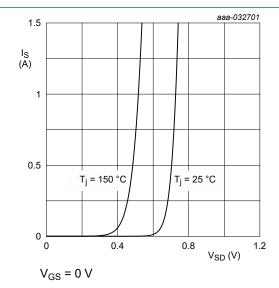
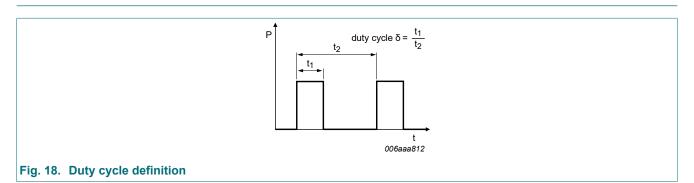


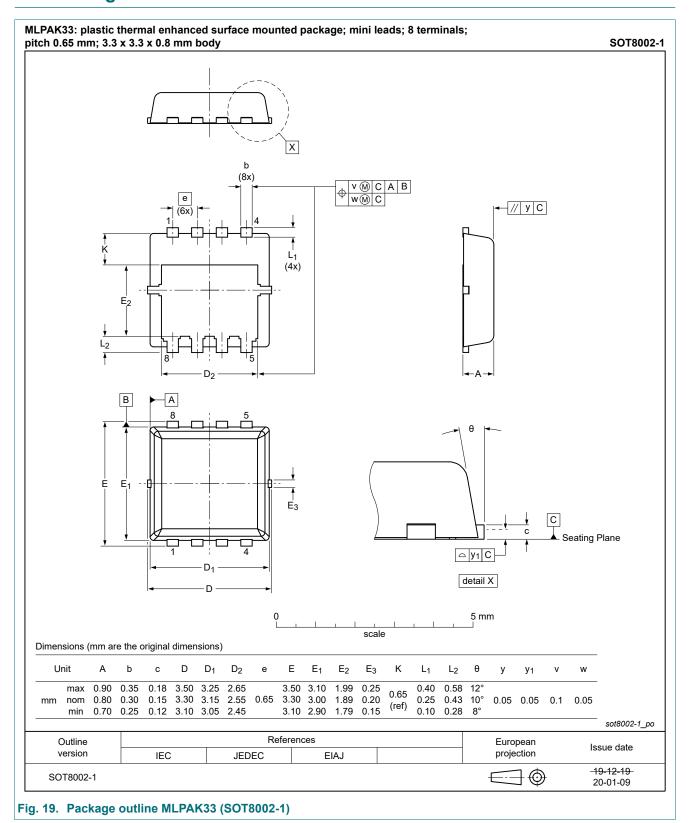
Fig. 17. Source current as a function of source-drain voltage; typical values

### 11. Test information



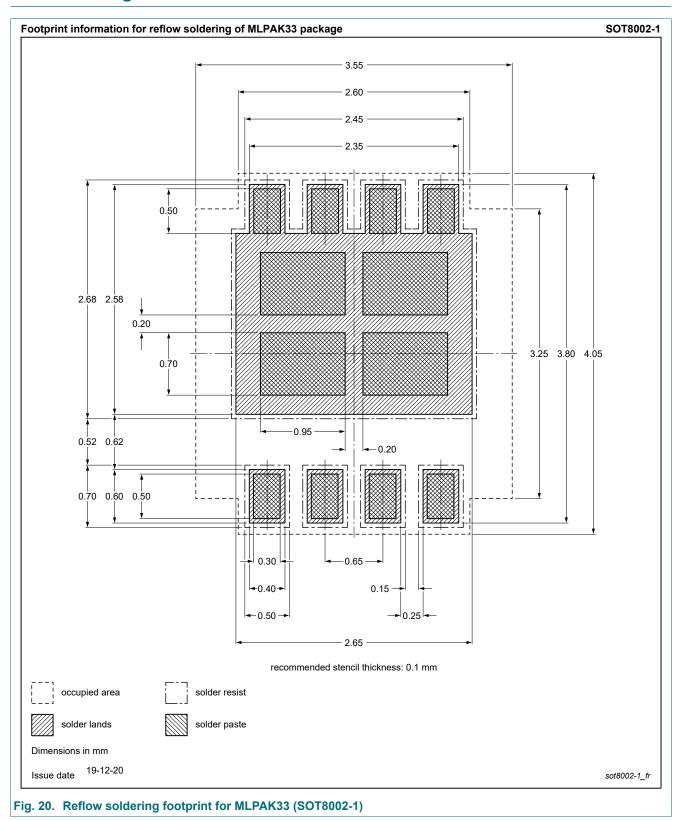
30 V, N-channel Trench MOSFET

# 12. Package outline



30 V, N-channel Trench MOSFET

# 13. Soldering



30 V, N-channel Trench MOSFET

# 14. Revision history

#### **Table 8. Revision history**

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PXN9R0-30QL v.1	20210105	Product data sheet	-	-

#### 30 V, N-channel Trench MOSFET

## 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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